

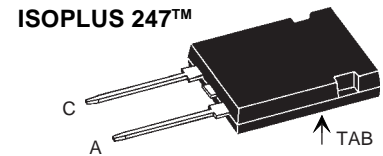
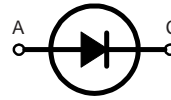
# HiPerFRED™ Epitaxial Diode with soft recovery

$$I_{FAV} = 60 \text{ A}$$

$$V_{RRM} = 1200 \text{ V}$$

$$t_{rr} = 40 \text{ ns}$$

$V_{RSM}$ V	$V_{RRM}$ V	Type
1200	1200	DSEP 60-12AR



A = Anode, C = Cathode

Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$ $I_{FAVM}$	$T_C = 90^\circ\text{C}$ ; rectangular, $d = 0.5$	70 60	A A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sine	500	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = 14.5 \text{ A}$ ; $L = 180 \mu\text{H}$	23	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive	1.5	A
$T_{VJ}$		-55...+175	$^\circ\text{C}$
$T_{VJM}$		175	$^\circ\text{C}$
$T_{stg}$		-55...+150	$^\circ\text{C}$
$P_{tot}$	$T_C = 25^\circ\text{C}$	190	W
$M_f$	mounting force	20...120	N
Weight	typical	6	g

### Features

- International standard package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour
- Epoxy meets UL 94V-0

### Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low  $I_{RM}$  reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Dimensions see Outlines.pdf

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$ ①	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ ; $T_{VJ} = 150^\circ\text{C}$		650 $\mu\text{A}$ 2.5 mA
$V_F$ ②	$I_F = 60 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$		1.74 V 2.66 V
$R_{thJC}$ $R_{thCH}$		0.25	0.8 K/W K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 300 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	40	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 130 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ ; $T_{VJ} = 100^\circ\text{C}$	7	14.3 A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
② Pulse Width = 300  $\mu\text{s}$ , Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified.

IXYS reserves the right to change limits, test conditions and dimensions.